

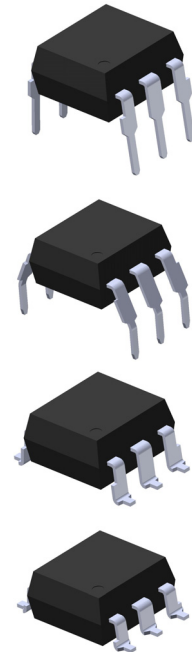


6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

TIL11X Series MCT2X Series

Features

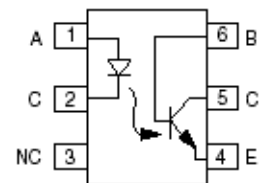
- TIL11X series: TIL111, TIL117
- MCT2X series: MCT2, MCT2E
- High isolation voltage between input and output
Viso = 5000 Vrms
- Creepage distance >7.6mm
- Compact dual-in-line package
- Operating temperature up to +110°C
- Pb free and RoHS compliant.
- UL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approval
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CSA approved
- CQC approved



Description

The TIL11X series and MCT2X series of devices each consist of an infrared emitting diode optically coupled to a phototransistor detector. They are packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

Schematic



1. Anode
2. Cathode
3. No Connection
4. Emitter
5. Collector
6. Base

Applications

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs
- Appliance system
- Industrial controls

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Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	60	mA
	Peak forward current ($t = 10\mu\text{s}$)	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P_D	100	mW
	Derating factor (above 100°C)		3.8	mW/ $^{\circ}\text{C}$
Output	Collector power dissipation	P_C	150	mW
	Derating factor (above 100°C)		9.0	mW/ $^{\circ}\text{C}$
	Collector-Emitter voltage	V_{CEO}	80	V
	Collector-Base voltage	V_{CBO}	80	V
	Emitter-Collector voltage	V_{ECO}	7	V
Total power dissipation		P_{tot}	200	mW
Isolation voltage ^{*2}		V_{iso}	5000	V _{rms}
Operating temperature		T_{opr}	-55~+110	$^{\circ}\text{C}$
Storage temperature		T_{stg}	-55~+125	$^{\circ}\text{C}$
Soldering temperature ^{*3}		T_{sol}	260	$^{\circ}\text{C}$

Notes

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together.

*2 For 10 seconds.

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Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless specified otherwise)

Input

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Condition
Forward voltage	TIL111	V _F	-	1.22	1.4	V	I _F = 16mA
	TIL117		-	-	1.4		T _A =0-70°C, I _F = 16mA
			-	1.32	-		T _A = -55°C, I _F = 16mA
			-	1.1	-		T _A =110°C, I _F = 16mA
	MCT2 MCT2E		-	1.23	1.5		I _F = 20mA
Reverse current		I _R	-	-	10	µA	V _R = 6V

Output

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector-Base dark current		I_{CBO}	-	-	20	nA	$V_{CB} = 10\text{V}$
Collector-Emitter dark current	All	I_{CEO}	-	1	50	nA	$V_{CE} = 10\text{V}$, $I_F = 0\text{mA}$
	TIL117		-	0.2	50	nA	$V_{CE} = 30\text{V}$, $I_F = 0\text{mA}$, $T_A=70^{\circ}\text{C}$
Collector-Emitter breakdown voltage		BV_{CEO}	80	-	-	V	$I_C = 1\text{mA}$
Collector-Base breakdown voltage		BV_{CBO}	80	-	-	V	$I_C = 0.01\text{mA}$
Emitter-Collector breakdown voltage		BV_{ECO}	7	-	-	V	$I_E = 0.1\text{mA}$
Emitter-Base breakdown voltage		BV_{EBO}	7	-	-	V	$I_E = 0.1\text{mA}$

Transfer Characteristics

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector current (Phototransistor operation)	TIL111	$I_{C(ON)}$	2	-	-	mA	$I_F = 16\text{mA}$, $V_{CE} = 0.4\text{V}$
Collector current (Photodiode operation)			7	-	-	μA	$I_F = 16\text{mA}$, $V_{CB} = 0.4\text{V}$
Current Transfer Ratio	TIL117	CTR	50	-	-	%	$I_F = 10\text{mA}$, $V_{CE} = 10\text{V}$
	MCT2 MCT2E		20	-	-		$I_F = 10\text{mA}$, $V_{CE} = 10\text{V}$

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Transfer Characteristics

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector-Emitter saturation voltage	All	$V_{CE(sat)}$	-	-	0.4	V	$I_F = 16mA, I_C = 2mA$
	TIL117		-	-	0.4		$I_F = 10mA, I_C = 0.5mA$
Isolation resistance		R_{IO}	10^{11}	-	-	Ω	$V_{IO} = 500Vdc$
Input-output capacitance		C_{IO}	-	-	2	pF	$V_{IO} = 0, f = 1MHz$
Turn-on time	TIL117	T_{on}	-	10	12	μs	$V_{CC} = 10V,$ $I_C = 2mA, R_L = 100\Omega$
Turn-off time	TIL117	T_{off}	-	9	12		
Rise time	TIL117 TIL111	t_r	-	6	10		
Fall time	TIL117 TIL111	t_f	-	8	10		
Turn-on time	MCT2 MCT2E	T_{on}	-	3	10	μs	$V_{CC} = 10V,$ $I_F = 10mA, R_L = 100\Omega$
Turn-off time	MCT2 MCT2E	T_{off}	-	3	10		
Rise time	MCT2 MCT2E	t_r	-	3	10		
Fall time	MCT2 MCT2E	t_f	-	3	10		

* Typical values at $T_a = 25^\circ C$

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TIL11X Series MCT2X Series

Typical Performance Curves

Figure 1. Forward Current vs Forward Voltage

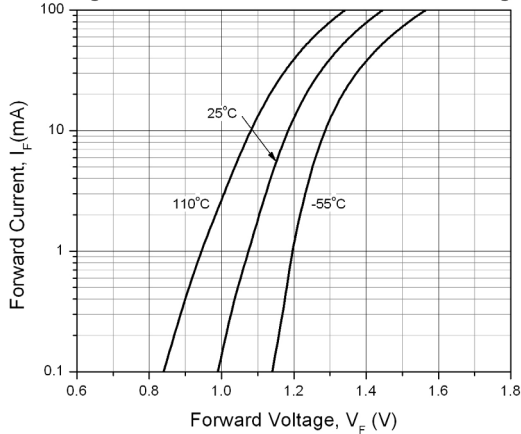


Figure 2. Current Transfer Ratio vs Forward Current

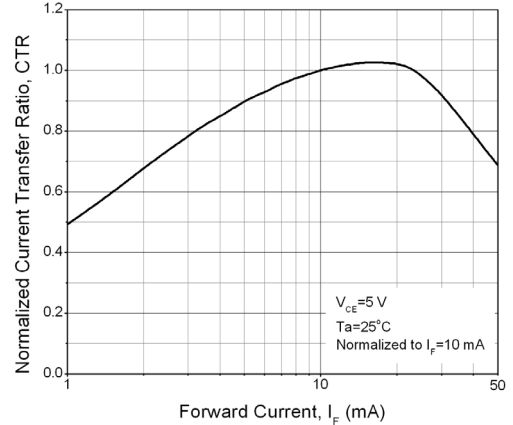


Figure 3. Current Transfer Ratio vs Ambient Temperature

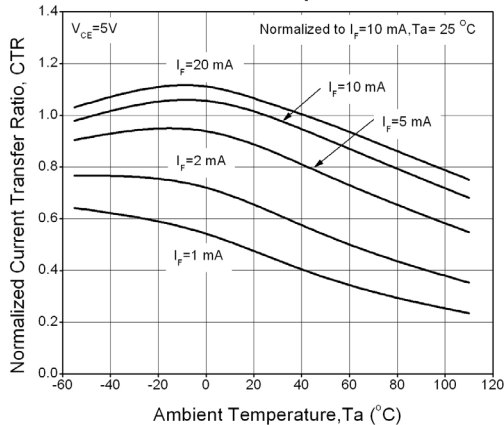


Figure 4. Current Transfer Ratio (Saturated) vs Base-Emitter Resistance

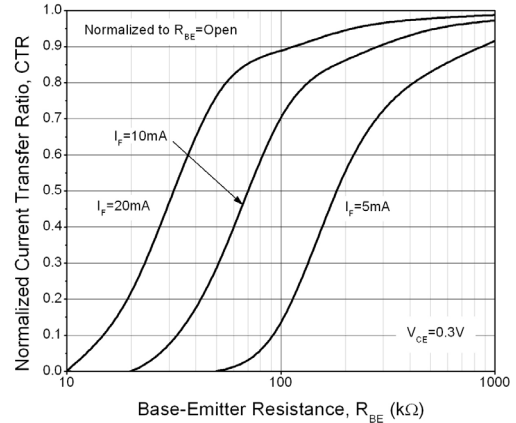


Figure 5. Current Transfer Ratio (Unsaturated) vs Base-Emitter Resistance

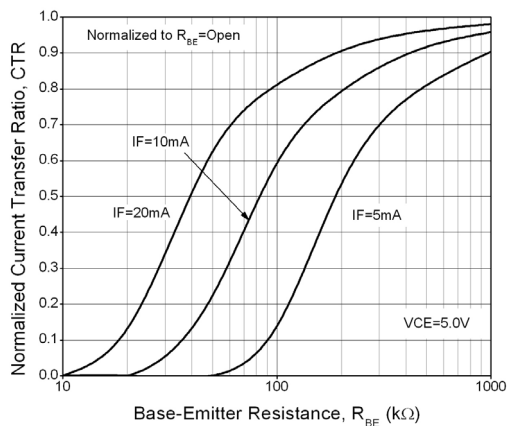
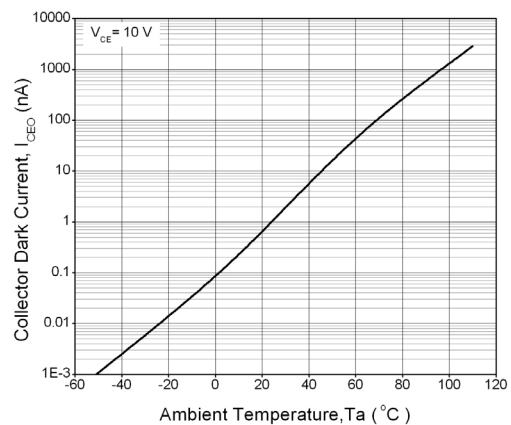


Figure 6. Dark Current vs Ambient Temperature



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Figure 7. Collector-Emitter Saturation Voltage vs Collector Current

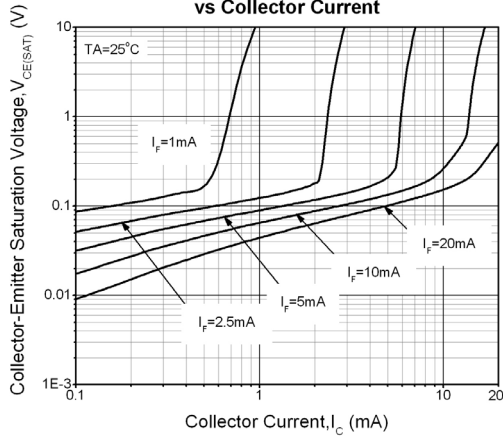


Figure 8. Switching Time vs Load Resistance

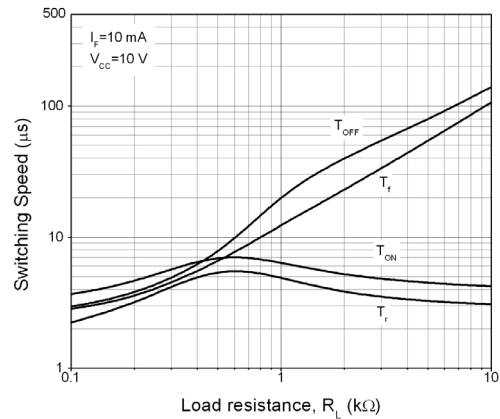


Figure 9. Turn-on Time vs Base-Emitter Resistance

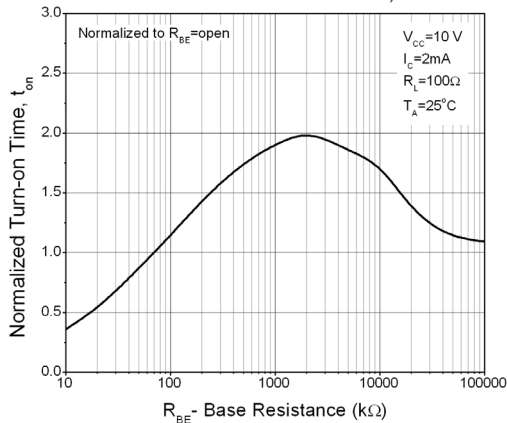


Figure 10. Turn-off Time vs Base-Emitter Resistance

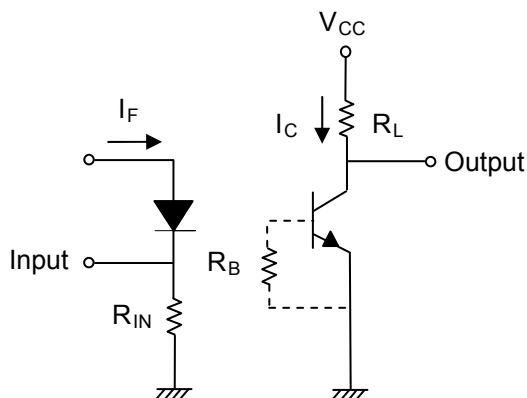
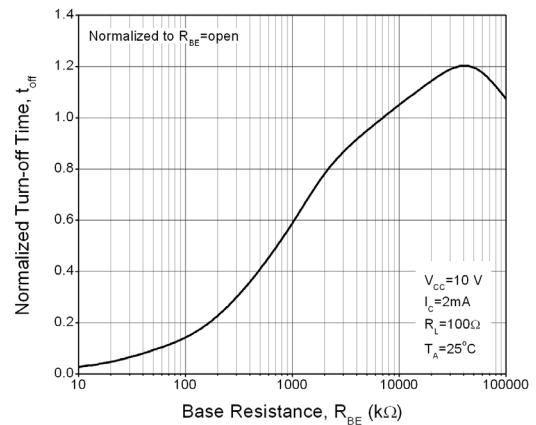


Figure 11. Switching Time Test Circuit & Waveforms

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**TIL11X Series
MCT2X Series**

Order Information

Part Number

TIL11XY(Z)-V
or
MCT2XY(Z)-V

Note

- X = Part no. for MCT2X series (E or none)
= Part no. for TIL11X series (1 or 7)
- Y = Lead form option (S, S1, M or none)
- Z = Tape and reel option (TA, TB or none).
- V = VDE safety (optional)

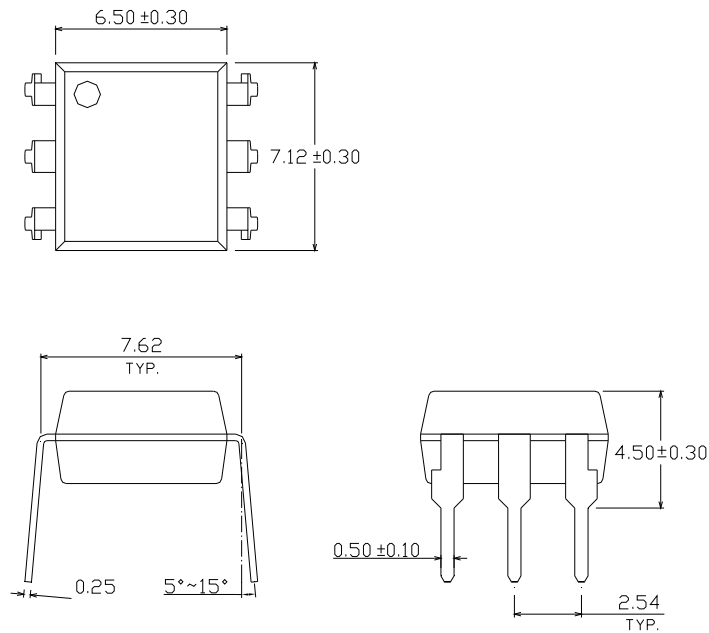
Option	Description	Packing quantity
None	Standard DIP-6	65 units per tube
M	Wide lead bend (0.4 inch spacing)	65 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel

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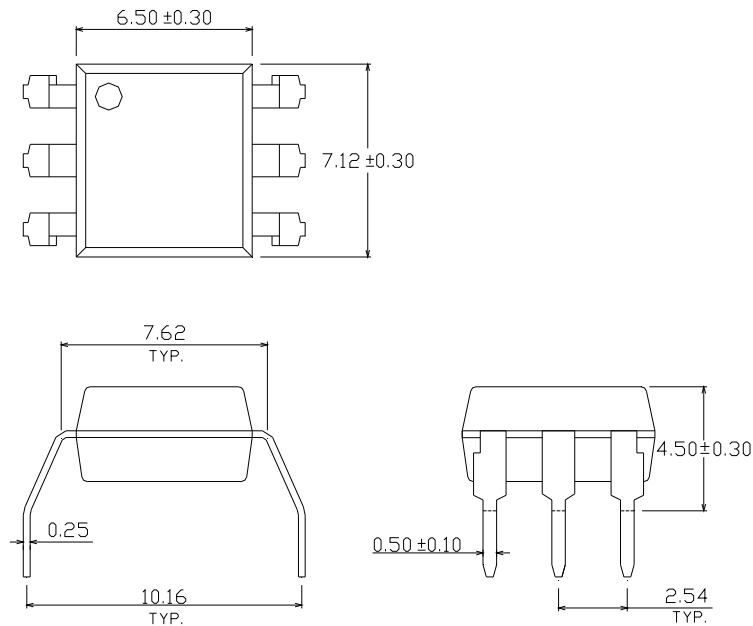
**TIL11X Series
MCT2X Series**

Package Drawings (Dimensions in mm)

Standard DIP Type



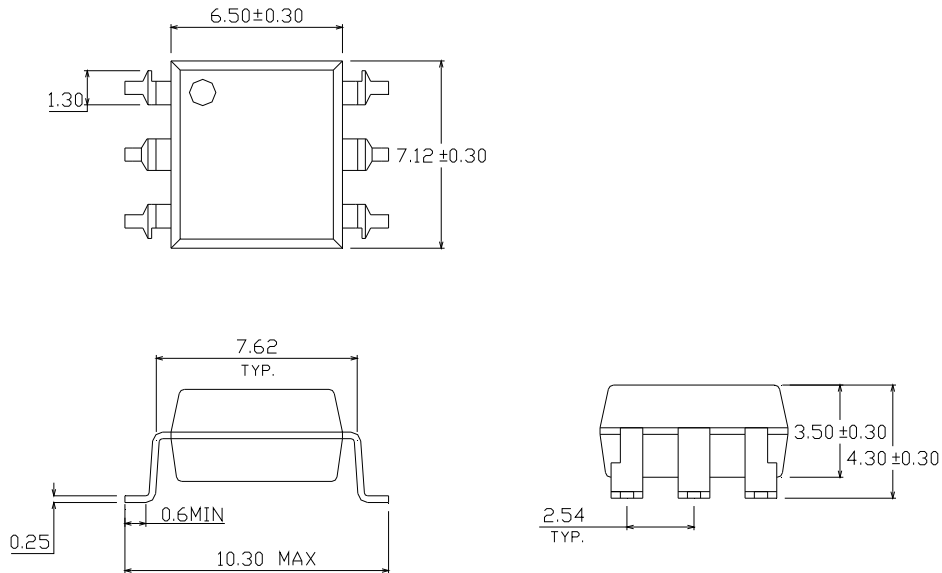
Option M Type



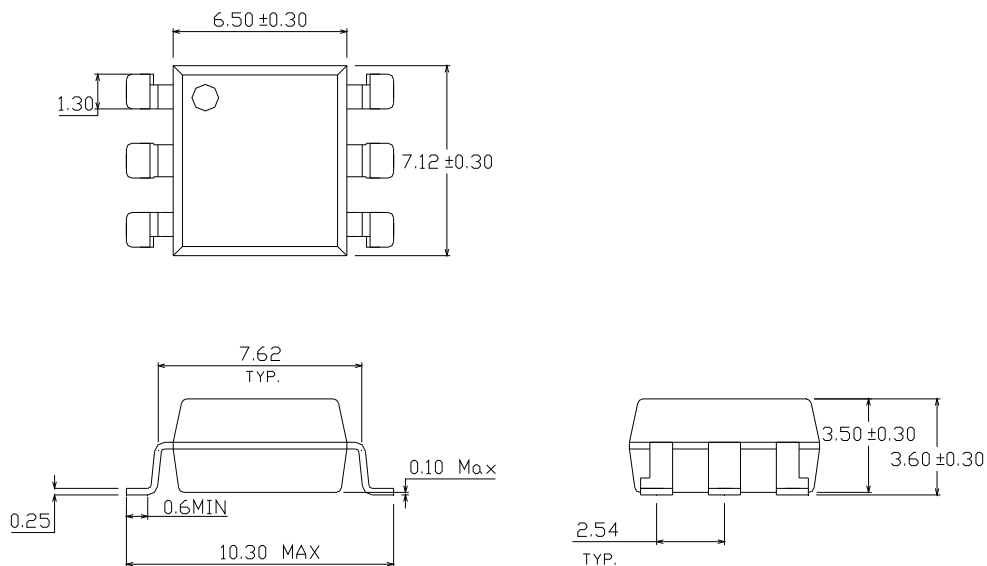
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**TIL11X Series
MCT2X Series**

Option S Type



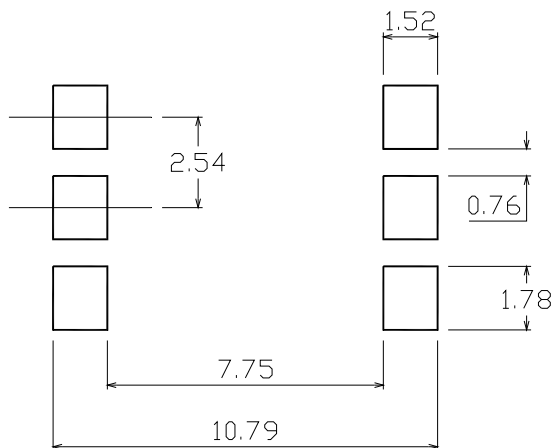
Option S1 Type



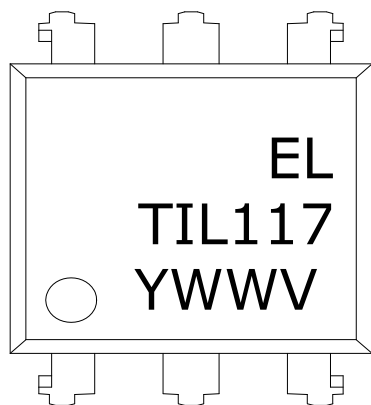
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**TIL11X Series
MCT2X Series**

Recommended pad layout for surface mount leadform



Device Marking



Notes

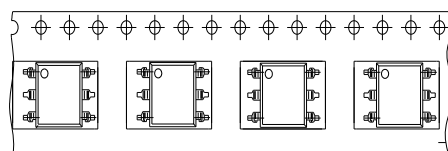
EL denotes Everlight
TIL117 denotes Device Number
Y denotes 1 digit Year code
WW denotes 2 digit Week code
V denotes VDE optional

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**TIL11X Series
MCT2X Series**

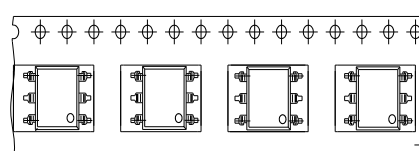
Tape & Reel Packing Specifications

Option TA



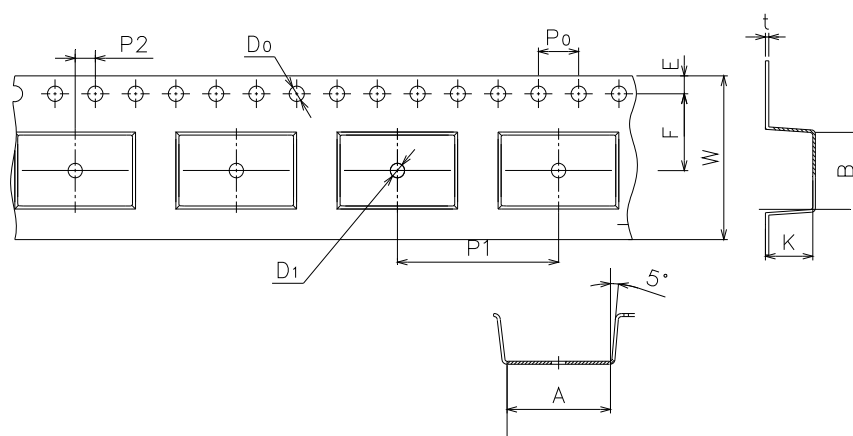
Direction of feed from reel

Option TB



Direction of feed from reel

Tape dimensions



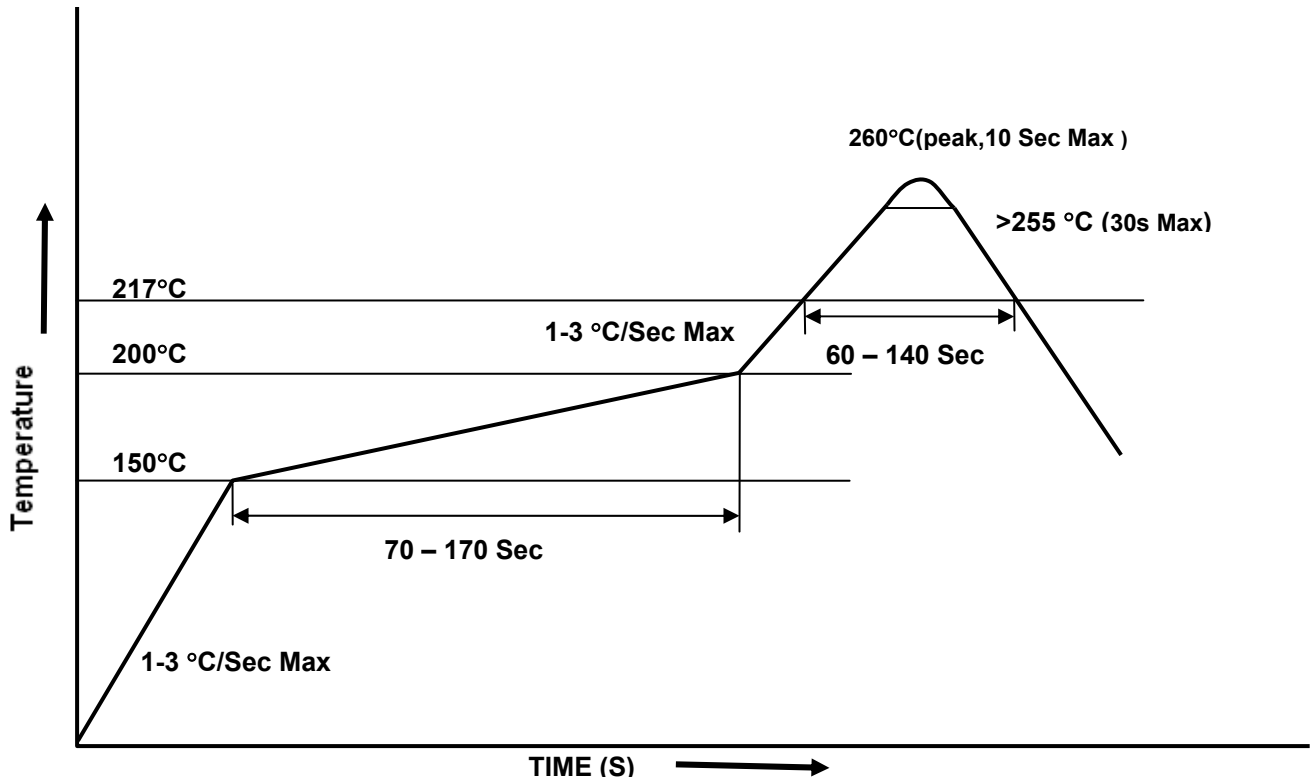
Dimension No.	A	B	Do	D1	E	F
Dimension (mm)	10.4±0.1	7.52±0.1	1.5±0.1	1.5+0.1/-0	1.75±0.1	7.5±0.1

Dimension No.	Po	P1	P2	t	W	K
Dimension (mm)	4.0±0.15	16.0±0.1	2.0±0.1	0.35±0.03	16.0±0.2	4.5±0.1

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**TIL11X Series
MCT2X Series**

Solder Reflow Temperature Profile



6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**TIL11X Series
MCT2X Series**

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